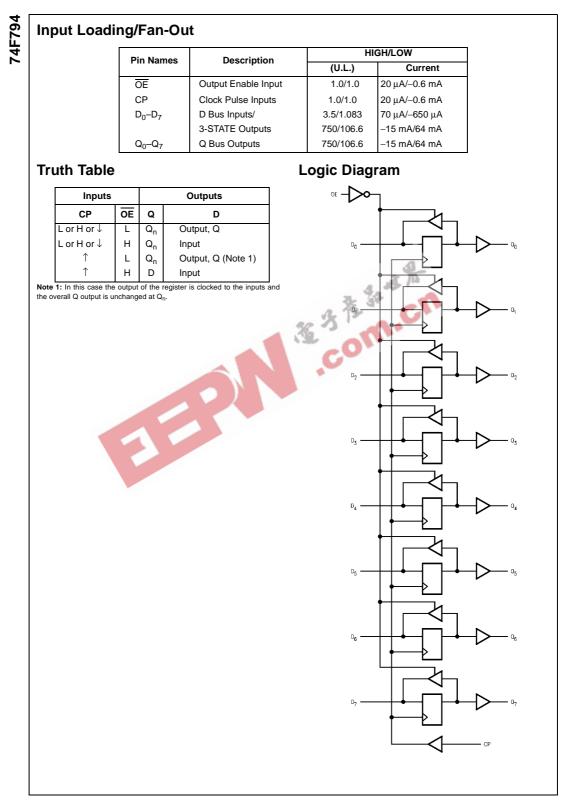


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Absolute Maximum Ratings(Note 2)		Recommended Operating				
Storage Temperature	$-65^{\circ}C$ to $+$ 150°C	Conditions				
Ambient Temperature under Bias	$-55^{\circ}$ to $+125^{\circ}C$	Free Air Ambient Temperature	0°C to 70°C			
Junction Temperature under Bias	$-55^{\circ}C$ to $+150^{\circ}C$	Supply Voltage	+4.5V to +5.5V			
V <sub>CC</sub> Pin Potential to Ground Pin	-0.5V to +7.0V					
Input Voltage (Note 3)	-0.5V to +7.0V					
Input Current (Note 3)	-30 mA to +5.0 mA					
ESD Last Passing Voltage (Min)	4000V					
Voltage Applied to Output						
In HIGH State (with $V_{CC} = 0V$ )		Note 2: Absolute maximum ratings are values	beyond which the device			
Standard Output	–0.5V to $V_{\mbox{\scriptsize CC}}$	may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.				
3-STATE Output	-0.5V to +5.5V	Note 3: In this case the output of the register is	clocked to the inputs and			
Current Applied to Output		the overall Q output is unchanged at $Q_n$ .				
in LOW State (Max)	Twice the Rated I <sub>OL</sub> (mA)	Note 4: Either voltage limit or current limit is suff	icient to protect inputs.			

## DC Electrical Characteristics over Operating Temperature Range unless otherwise specified

Symbol	Parameter	Min	Тур	Max	Units	Vcc	Conditions
V <sub>IH</sub>	Input HIGH Voltage	2.0			V	<u> </u>	Recognized as a HIGH Signal
V <sub>IL</sub>	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V <sub>CD</sub>	Input Clamp Diode Voltage			-1.2	v	Min	I <sub>IN</sub> = -18 mA
V <sub>ОН</sub>	Output HIGH Voltage	2.4 2.0	2.8 2.44		CV	Min	I <sub>OH</sub> = -3 mA I <sub>OH</sub> = -15 mA
V <sub>OL</sub>	Output LOW Voltage		0.45	0.55	v	Min	I <sub>OL</sub> = 64 mA
Ін	Input HIGH Current			5.0	μΑ	Max	$V_{IN} = 2.7V$
I <sub>BVI</sub>	Input HIGH Current Breakdown Test			7.0	μΑ	Max	$V_{IN} = 7.0V \ (\overline{OE}, \ CP)$
BVIT	Input HIGH Current Breakdown (I/O)			0.5	mA	Max	$V_{IN} = 5.5V (D_n)$
ICEX	Output HIGH Leakage Current			50	μΑ	Max	$V_{OUT} = V_{CC}$
V <sub>ID</sub>	Input Leakage Test	4.75			v	0.0	I <sub>ID</sub> = 1.9 μA All Other Pins Grounded
I <sub>OD</sub>	Output Leakage Circuit Current			3.75	μΑ	0.0	V <sub>IOD</sub> = 150 mV All Other Pins Grounded
IIL	Input LOW Current			-0.6	mA	Max	V <sub>IN</sub> = 0.5V (OE, CP)
os	Output Short- Circuit Current	-100		-225	mA	Max	V <sub>OUT</sub> = 0V
Iн + Оzн	Output Leakage Current			70	μΑ	Max	V <sub>OUT</sub> = 2.7V (Dn)
IL <sup>+</sup> OZL	Output Leakage Current			-650	μΑ	Max	V <sub>OUT</sub> = 0.5V (Dn)
V <sub>ID</sub>	Input Leakage Test	4.75			v	0.0	I <sub>ID</sub> = 1.9 μA All Other Pins Grounded
OD	Output Circuit Leakage Current			3.75	μΑ	0.0	V <sub>IOD</sub> = 150 mV All Other Pins Grounded
ZZ	Bus Drainage Test			100	μΑ	0.0	$V_{OUT} = 5.25V$
ССН	Power Supply Current			65	mA	Max	V <sub>O</sub> = HIGH
CCL	Power Supply Current			80	mA	Max	$V_0 = LOW$
CCZ	Power Supply Current			80	mA	Max	V <sub>O</sub> = HIGH Z

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## **AC Electrical Characteristics**

	Symbol Parameter		$T_{A} = +25^{\circ}C$ $V_{CC} = +5.0V$ $C_{L} = 50 \text{ pF}$			$T_{A} = 0^{\circ}C \text{ to } +70^{\circ}C$ $V_{CC} = +5.0V$ $C_{L} = 50 \text{ pF}$	
	Min	Тур	Max	Min	Max	1	
f <sub>MAX</sub>	Maximum Clock Frequency	90			90		MHz
t <sub>PLH</sub>	Propagation Delay	2.5		7.0	2.5	8.0	ns
t <sub>PHL</sub>	CP to Q <sub>n</sub>	2.5		8.0	2.5	9.0	
t <sub>PZH</sub>	Output Enable Time	2.3		8.5	2.0	9.0	ns
t <sub>PZL</sub>		2.0		10.0	2.0	10.5	
t <sub>PHZ</sub>	Output Disable Time	1.0		7.0	1.0	8.0	ns
t <sub>PLZ</sub>		1.0		7.0	1.0	8.0	
t <sub>S</sub> (H)	Setup Time, HIGH or LOW	4.0			4.0		
t <sub>S</sub> (L)	Bus to Clock	4.0			4.0		ns
t <sub>H</sub> (H)	Hold Time, HIGH or LOW	1.5			1.5		1
t <sub>H</sub> (L)	Bus to Clock	1.5			1.5		ns
t <sub>W</sub> (H	Clock Pulse Width	5.8			5.8		
	HIGH or LOW	5.8			5.8		ns
		5.8 5.8	うき (0)	m.c	'n		

